



# FGH40N60SMDF

## 600V, 40A Field Stop IGBT

### Features

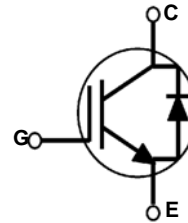
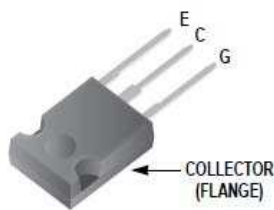
- Maximum Junction Temperature :  $T_J = 175^{\circ}\text{C}$
- Positive Temperature Co-efficient for easy parallel operating
- High current capability
- Low saturation voltage:  $V_{CE(sat)} = 1.9\text{V(Typ.)}$  @  $I_C = 40\text{A}$
- High input impedance
- Fast switching
- Tighten Parameter Distribution
- RoHS compliant

### General Description

Using Novel Field Stop IGBT Technology, Fairchild's new series of Field Stop IGBTs offer the optimum performance for Solar Inverter, UPS, SMPS, IH and PFC applications where low conduction and switching losses are essential.

### Applications

- Solar Inverter, UPS, SMPS, PFC
- Induction Heating



### Absolute Maximum Ratings

Symbol	Description	Ratings	Units
$V_{CES}$	Collector to Emitter Voltage	600	V
$V_{GES}$	Gate to Emitter Voltage	$\pm 20$	V
$I_C$	Collector Current @ $T_C = 25^{\circ}\text{C}$	80	A
	Collector Current @ $T_C = 100^{\circ}\text{C}$	40	A
$I_{CM(1)}$	Pulsed Collector Current	120	A
$I_F$	Diode Forward Current @ $T_C = 25^{\circ}\text{C}$	40	A
	Diode Forward Current @ $T_C = 100^{\circ}\text{C}$	20	A
$I_{FM(1)}$	Pulsed Diode Maximum Forward Current	120	A
$P_D$	Maximum Power Dissipation @ $T_C = 25^{\circ}\text{C}$	349	W
	Maximum Power Dissipation @ $T_C = 100^{\circ}\text{C}$	174	W
$T_J$	Operating Junction Temperature	-55 to +175	$^{\circ}\text{C}$
$T_{stg}$	Storage Temperature Range	-55 to +175	$^{\circ}\text{C}$
$T_L$	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds	300	$^{\circ}\text{C}$

**Notes:**

1: Repetitive rating: Pulse width limited by max. junction temperature

## Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Units
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction to Case	-	0.43	$^{\circ}C/W$
$R_{\theta JC}(Diode)$	Thermal Resistance, Junction to Case	-	1.45	$^{\circ}C/W$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	-	40	$^{\circ}C/W$

## Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FGH40N60SMDF	FGH40N60SMDF	TO-247	-	-	30

## Electrical Characteristics of the IGBT $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
<b>Off Characteristics</b>						
$BV_{CES}$	Collector to Emitter Breakdown Voltage	$V_{GE} = 0V, I_C = 250\mu A$	600	-	-	V
$\frac{\Delta BV_{CES}}{\Delta T_J}$	Temperature Coefficient of Breakdown Voltage	$V_{GE} = 0V, I_C = 250\mu A$	-	0.6	-	$V/^{\circ}C$
$I_{CES}$	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0V$	-	-	250	$\mu A$
$I_{GES}$	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0V$	-	-	$\pm 400$	nA
<b>On Characteristics</b>						
$V_{GE(th)}$	G-E Threshold Voltage	$I_C = 250\mu A, V_{CE} = V_{GE}$	3.5	4.5	6.0	V
$V_{CE(sat)}$	Collector to Emitter Saturation Voltage	$I_C = 40A, V_{GE} = 15V$	-	1.9	2.5	V
		$I_C = 40A, V_{GE} = 15V, T_C = 175^{\circ}C$	-	2.1	-	V
<b>Dynamic Characteristics</b>						
$C_{ies}$	Input Capacitance	$V_{CE} = 30V, V_{GE} = 0V, f = 1MHz$	-	1880	-	pF
$C_{oes}$	Output Capacitance		-	180	-	pF
$C_{res}$	Reverse Transfer Capacitance		-	50	-	pF
<b>Switching Characteristics</b>						
$t_{d(on)}$	Turn-On Delay Time	$V_{CC} = 400V, I_C = 40A, R_G = 6\Omega, V_{GE} = 15V, \text{Inductive Load}, T_C = 25^{\circ}C$	-	12	16	ns
$t_r$	Rise Time		-	20	28	ns
$t_{d(off)}$	Turn-Off Delay Time		-	92	120	ns
$t_f$	Fall Time		-	13	17	ns
$E_{on}$	Turn-On Switching Loss		-	1.3	2.0	mJ
$E_{off}$	Turn-Off Switching Loss		-	0.26	0.34	mJ
$E_{ts}$	Total Switching Loss		-	1.56	2.34	mJ
$t_{d(on)}$	Turn-On Delay Time	$V_{CC} = 400V, I_C = 40A, R_G = 6\Omega, V_{GE} = 15V, \text{Inductive Load}, T_C = 175^{\circ}C$	-	15	-	ns
$t_r$	Rise Time		-	22	-	ns
$t_{d(off)}$	Turn-Off Delay Time		-	116	-	ns
$t_f$	Fall Time		-	16	-	ns
$E_{on}$	Turn-On Switching Loss		-	2.1	-	mJ
$E_{off}$	Turn-Off Switching Loss		-	0.6	-	mJ
$E_{ts}$	Total Switching Loss		-	2.7	-	mJ

### Electrical Characteristics of the IGBT (Continued)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max	Units
$Q_g$	Total Gate Charge	$V_{CE} = 400V, I_C = 40A,$ $V_{GE} = 15V$	-	119	180	nC
$Q_{ge}$	Gate to Emitter Charge		-	13	20	nC
$Q_{gc}$	Gate to Collector Charge		-	58	90	nC

### Electrical Characteristics of the Diode $T_C = 25^\circ C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max	Units	
$V_{FM}$	Diode Forward Voltage	$I_F = 20A$	$T_C = 25^\circ C$	-	1.3	1.7	V
			$T_C = 175^\circ C$	-	1.15	-	
$E_{rec}$	Reverse Recovery Energy	$I_F = 20A, di_F/dt = 200A/\mu s$	$T_C = 175^\circ C$	-	138	-	uJ
$t_{rr}$	Diode Reverse Recovery Time		$T_C = 25^\circ C$	-	70	100	ns
			$T_C = 175^\circ C$	-	210	-	
$Q_{rr}$	Diode Reverse Recovery Charge		$T_C = 25^\circ C$	-	250	350	nC
		$T_C = 175^\circ C$	-	1875	-		

## Typical Performance Characteristics

Figure 1. Typical Output Characteristics

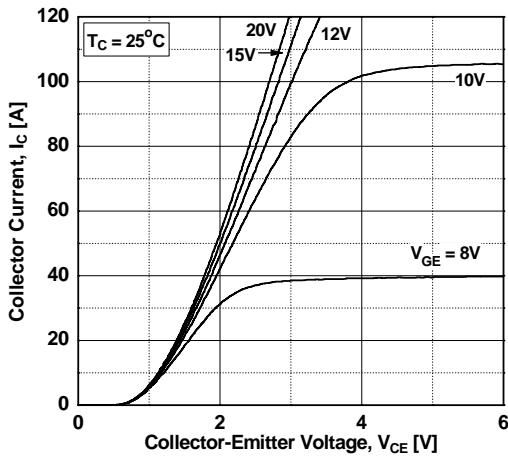


Figure 2. Typical Output Characteristics

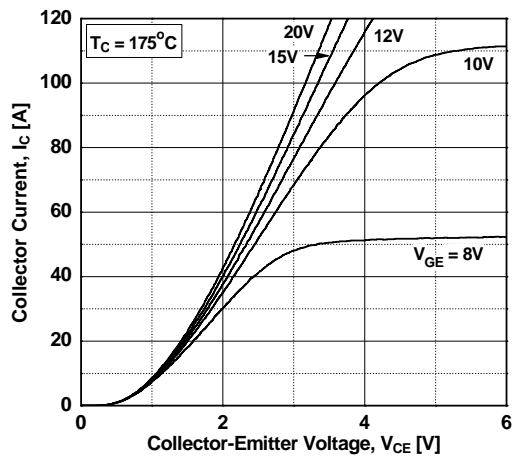


Figure 3. Typical Saturation Voltage Characteristics

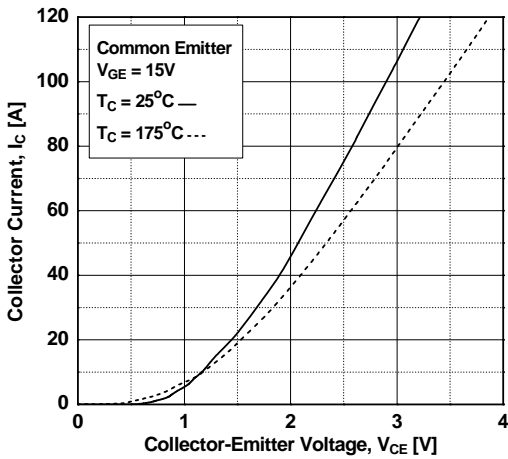


Figure 4. Transfer Characteristics

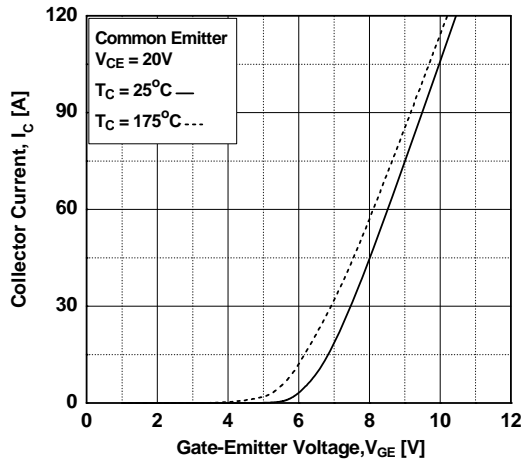


Figure 5. Saturation Voltage vs. Case Temperature at Variant Current Level

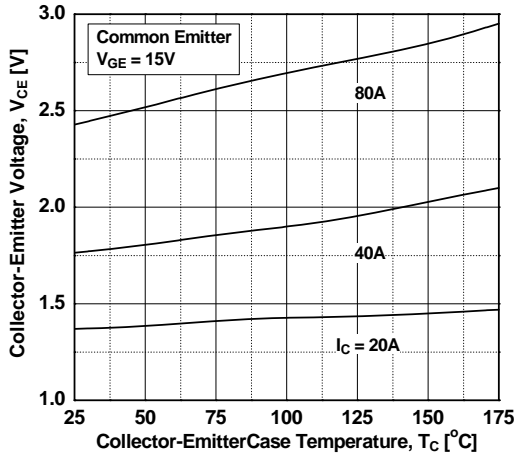
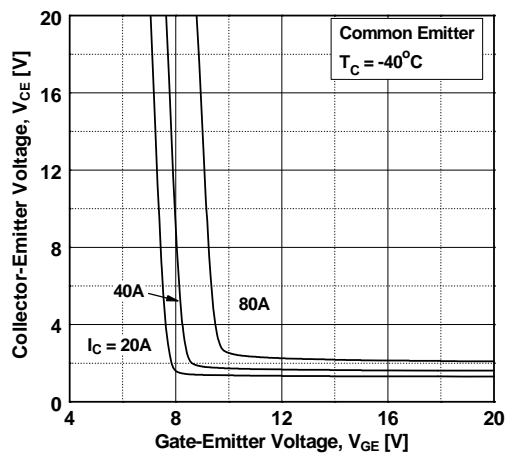


Figure 6. Saturation Voltage vs. Vge



## Typical Performance Characteristics

Figure 7. Saturation Voltage vs.  $V_{GE}$

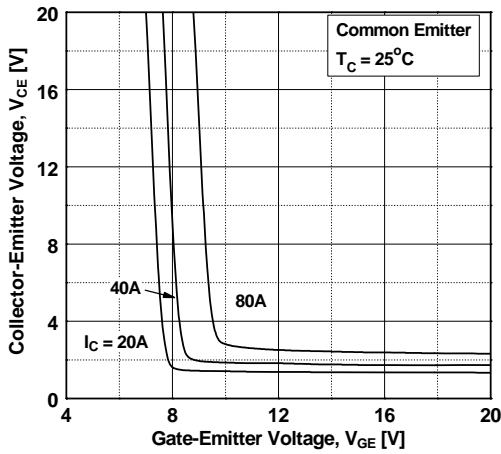


Figure 8. Saturation Voltage vs.  $V_{GE}$

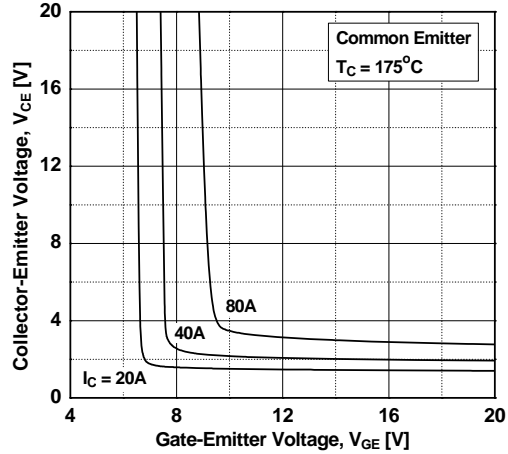


Figure 9. Capacitance Characteristics

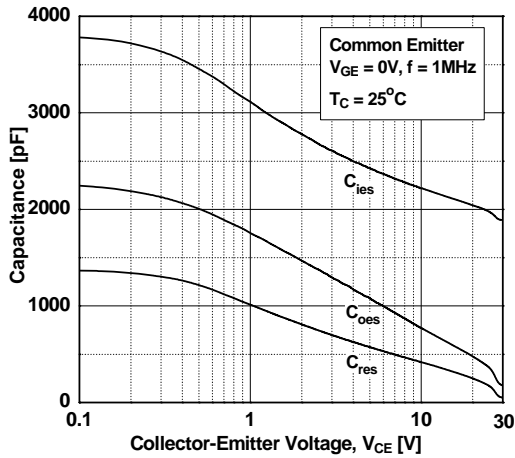


Figure 10. Gate charge Characteristics

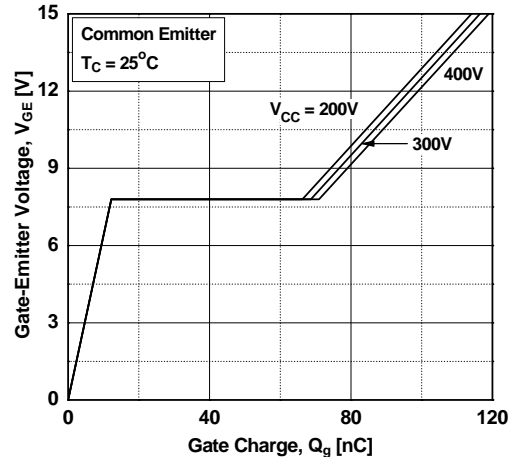


Figure 11. SOA Characteristics

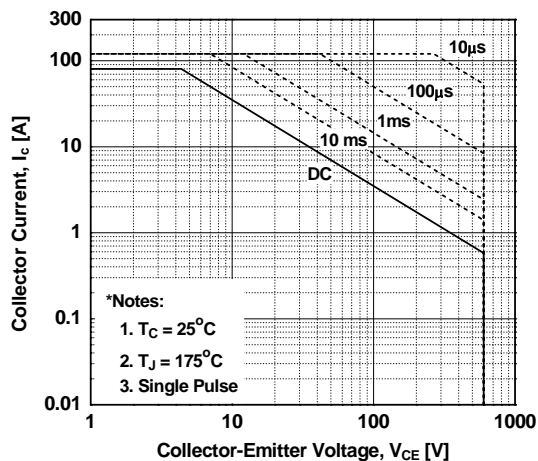
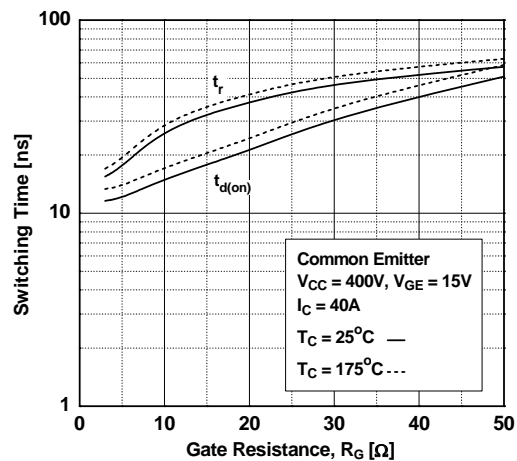


Figure 12. Turn-on Characteristics vs. Gate Resistance



## Typical Performance Characteristics

Figure 13. Turn-off Characteristics vs. Gate Resistance

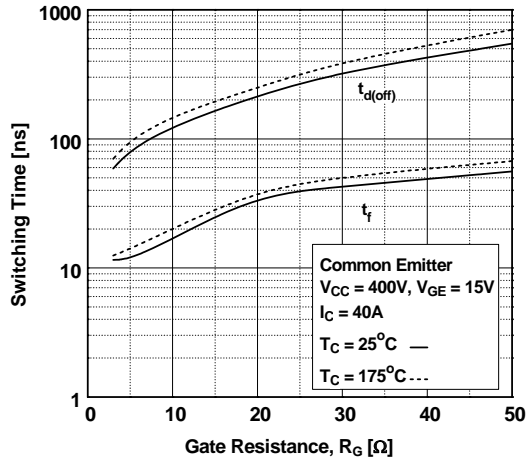


Figure 14. Turn-on Characteristics vs. Collector Current

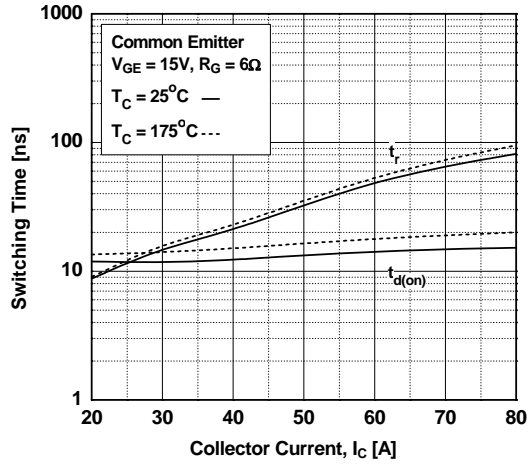


Figure 15. Turn-off Characteristics vs. Collector Current

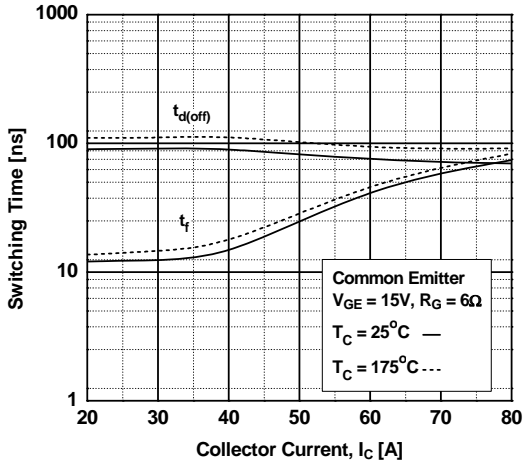


Figure 16. Switching Loss vs. Gate Resistance

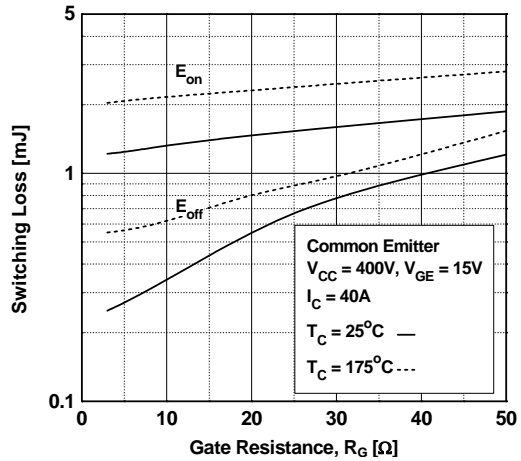


Figure 17. Switching Loss vs. Collector Current

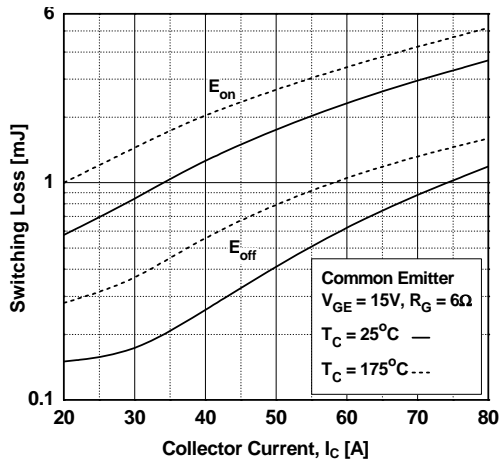
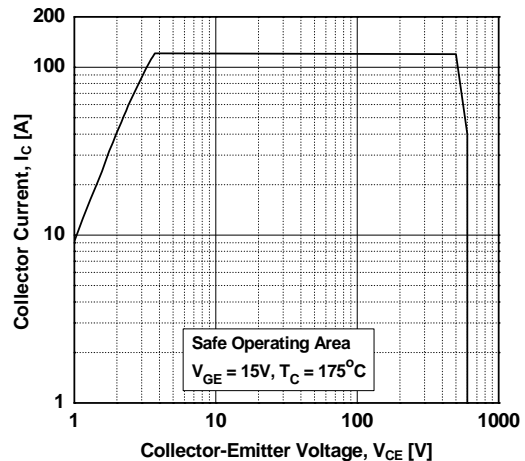


Figure 18. Turn off Switching SOA Characteristics



## Typical Performance Characteristics

Figure 19. Current Derating

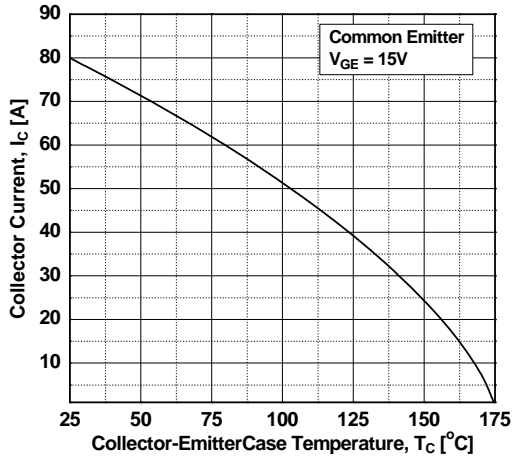


Figure 20. Load Current Vs. Frequency

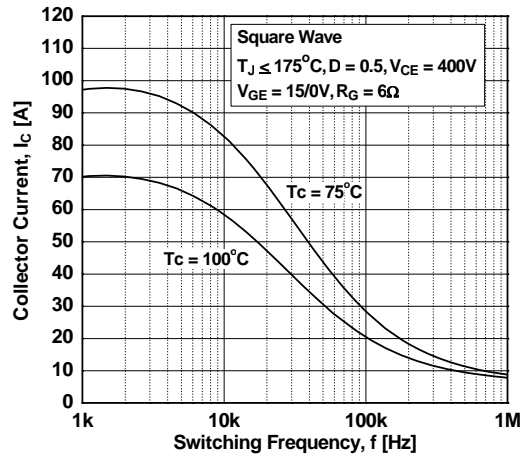


Figure 21. Forward Characteristics

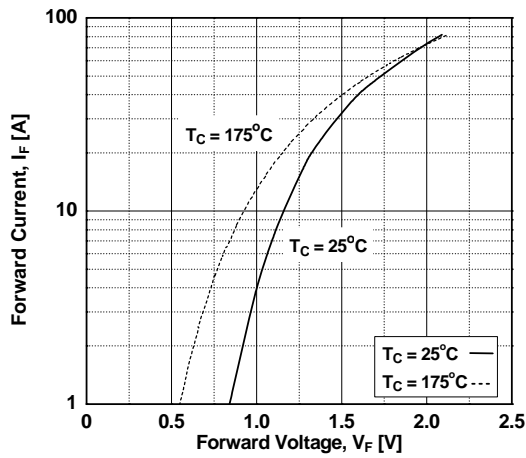


Figure 22. Reverse Current

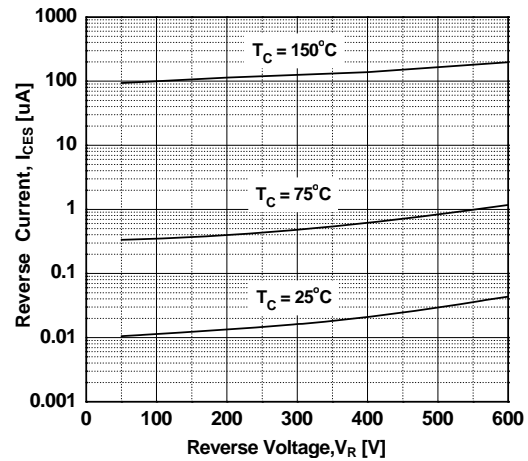


Figure 23. Stored Charge

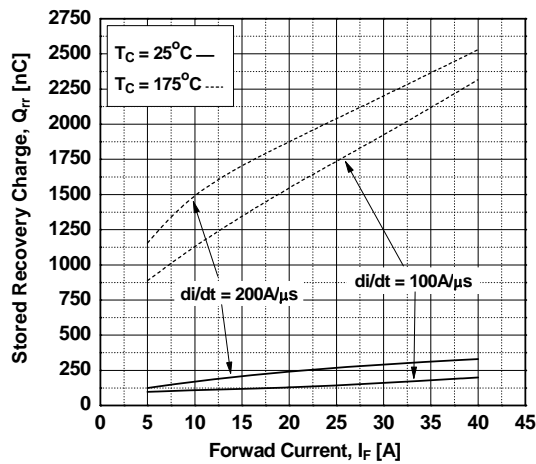
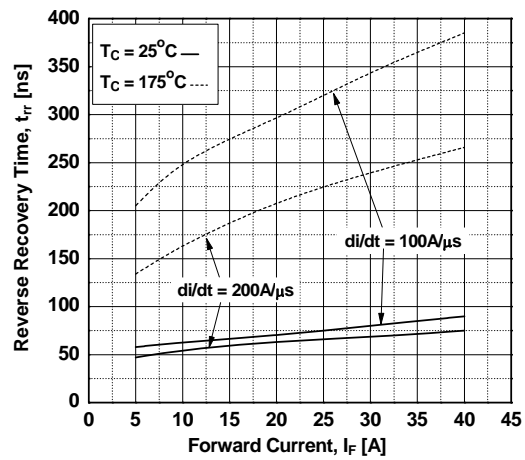
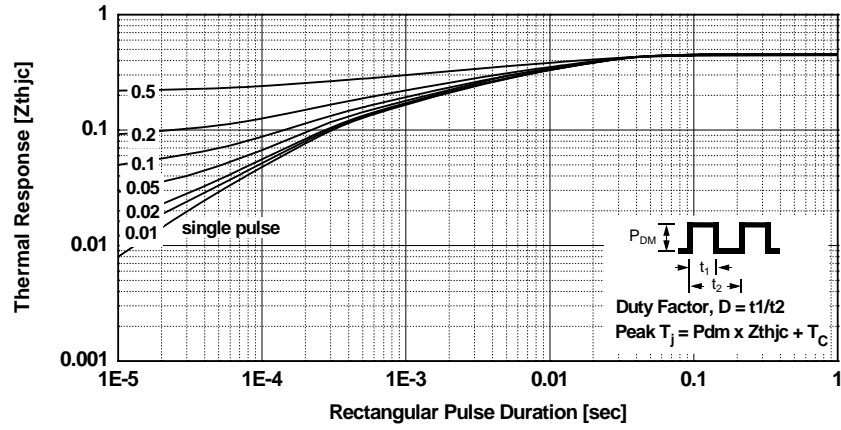


Figure 24. Reverse Recovery Time



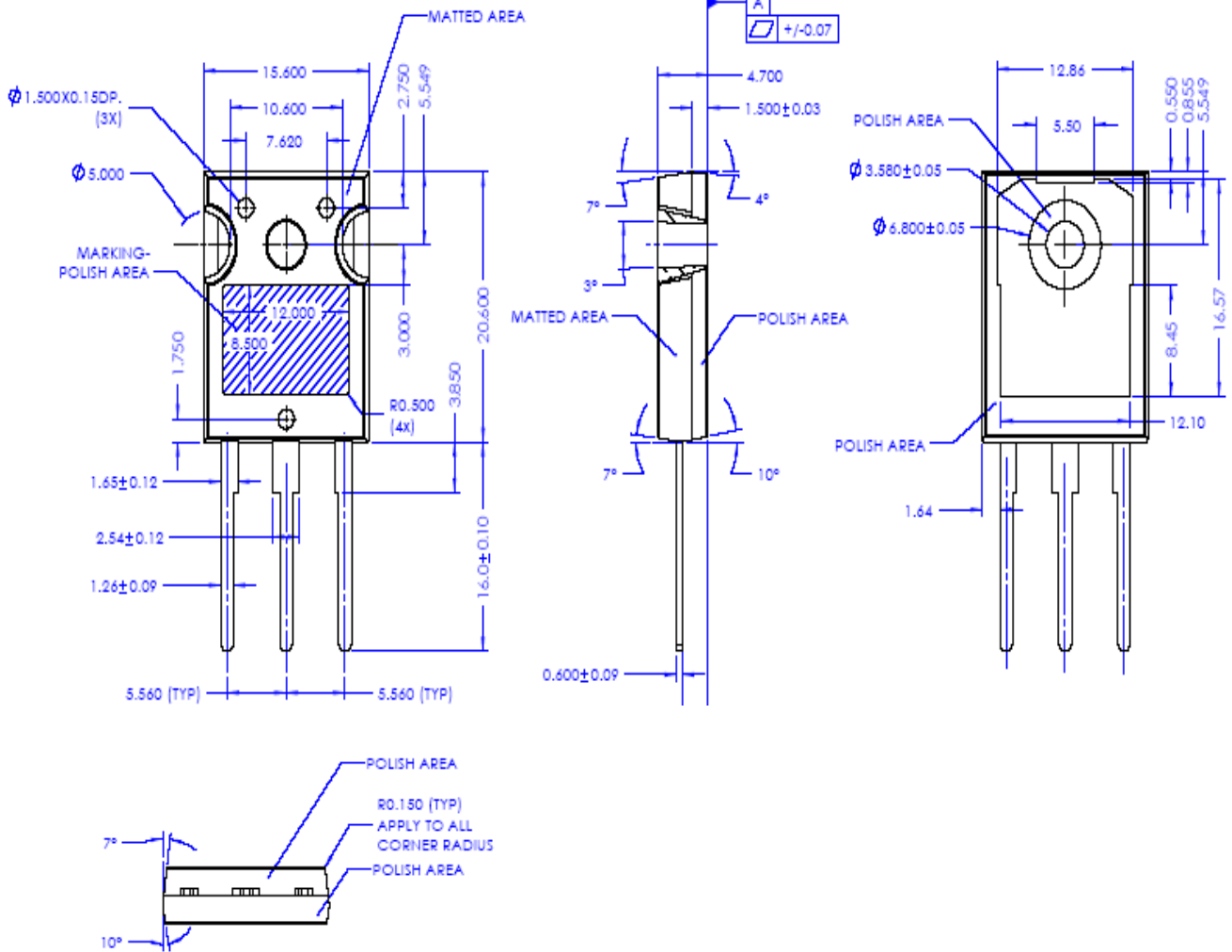
Typical Performance Characteristics

Figure 25. Transient Thermal Impedance of IGBT



**Mechanical Dimensions**

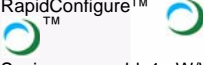




**TO - 247AB (FKS PKG CODE 001)**





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Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
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